# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



### Contact us

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### RFM products are now Murata products.

RO3300E

403.55 MHz

**SAW Resonator** 

#### Designed for 403.55 MHz MICs Transmitters

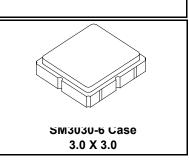
- Very Low Series Resistance
- · Quartz Stability
- Complies with Directive 2002/95/EC (RoHS)



The RO3300E is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount, ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 403.55 MHz.

### Absolute Maximum Ratings

Rating	Value	Units
Input Power Level	0	dBm
DC Voltage	12	VDC
Storage Temperature Range	-40 to +125	°C
Operating Temperature Range	-40 to +105	°C
Soldering Temperature (10 seconds / 5 cycles maximum)	260	°C



### **Electrical Characteristics**

Characteristic			Notes	Minimum	Typical	Maximum	Units
Center Frequency, +25 °C	Absolute Frequency	f <sub>C</sub>	0.045	403.475		403.625	MHz
	Tolerance from 403.55 MHz	$\Delta f_C$	2,3,4,5			±75	kHz
Insertion Loss		IL	2,5,6		1.0	2.0	dB
Quality Factor	Unloaded Q	Q <sub>U</sub>	5,6,7		8117		
	50 Ω Loaded Q	QL			768		
Temperature Stability	erature Stability Turnover Temperature T <sub>O</sub>		10	25	40	°C	
	Turnover Frequency	f <sub>O</sub>	6,7,8		f <sub>C</sub>		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	f <sub>A</sub>	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>			10.5		Ω
	Motional Inductance	L <sub>M</sub>	5, 7, 9		33.5		μH
	Motional Capacitance	CM			4.6		fF
	Shunt Static Capacitance	CO	5, 6, 9		4.2		pF
Test Fixture Shunt Inductance			2, 7		36.9		nH
Lid Symbolization (in addition	n to Lot and/or Date Codes)		719 // YWWS				
Standard Reel Quantity	Reel Size 7 Inch	10 500 Pieces/Reel			el		
	Reel Size 13 Inch		10	3000 Pieces/Reel			

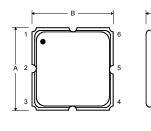
### CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. NOTES:

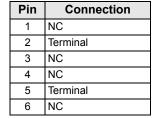
- Frequency aging is the change in  $\rm f_C$  with time and is specified at +65  $^\circ \rm C$  or less. 1. Aging may exceed the specification for prolonged temperatures above +65  $^\circ$ C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- The center frequency,  $f_{\text{C}}$ , is measured at the minimum insertion loss point,  $\text{IL}_{\text{MIN}}$ , 2 with the resonator in the 50  $\Omega$  test system (VSWR  $\leq$  1.2:1). The shunt inductance,  $L_{TEST}$  is tuned for parallel resonance with C<sub>O</sub> at f<sub>C</sub>. Typically,
- $f_{OSCILLATOR}$  or  $f_{TRANSMITTER}$  is approximately equal to the resonator  $f_{C}$ 3 One or more of the following United States patents apply: 4,454,488 and
- 4,616,197. government approval, which is the responsibility of the equipment manufacturer. Unless noted otherwise, case temperature  $T_c = +25 \pm 2$  °C. 4.
- 5
- 6. The design, manufacturing process, and specifications of this device are subject to change without notice.

- Derived mathematically from one or more of the following directly measured 7. parameters:  $f_C$ , IL, 3 dB bandwidth,  $f_C$  versus  $T_C$ , and  $C_O$ .
- Turnover temperature,  $T_O$ , is the temperature of maximum (or turnover) frequency,  $f_O$ . The nominal frequency at any case temperature,  $T_C$ , may be 8. calculated from:  $f = f_0 [1 - FTC (T_0 - T_C)^2]$ . Typically oscillator  $T_0$  is approximately equal to the specified resonator To.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance  $C_{\rm O}$  is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as:  $C_P \approx C_O - 0.05 \text{ pF.}$ 10.
  - Tape and Reel Standard Per ANSI / EIA 481.

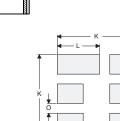
### **Electrical Connections**

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.





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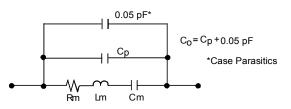
**4**— M →

н D –

### **Case and Typical PCB Land Dimensions**

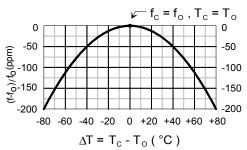
Ref	mm			Inches			
	Min	Nom	Max	Min	Nom	Max	
Α	2.87	3.00	3.13	0.113	0.118	0.123	
В	2.87	3.00	3.13	0.113	0.118	0.123	
С	1.12	1.25	1.38	0.044	0.049	0.054	
D	0.77	0.90	1.03	0.030	0.035	0.040	
E	2.67	2.80	2.93	0.105	0.110	0.115	
F	1.47	1.60	1.73	0.058	0.063	0.068	
G	0.72	0.85	0.98	0.028	0.033	0.038	
Н	1.37	1.50	1.63	0.054	0.059	0.064	
I	0.47	0.60	0.73	0.019	0.024	0.029	
J	1.17	1.30	1.43	0.046	0.051	0.056	
К		3.20			0.126		
L		1.70			0.067		
М		1.05			0.041		
Ν		0.81			0.032		
0		0.38			0.015		

### Equivalent RLC Model



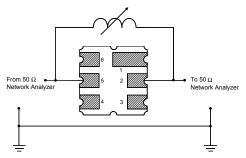
### **Temperature Characteristics**

The curve shown accounts for resonator contribution only and does not include external LC component temperature effects.

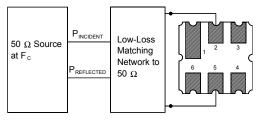


### **Characterization Test Circuit**

Inductor  $L_{TEST}$  is tuned to resonate with the static capacitance,  $C_{O}$ , at  $F_{C}$ .



### **Power Dissipation Test**



### **Example Application Circuits**

Typical Low-Power Transmitter Application

